

VXD Simulation and Reconstruction: Overview

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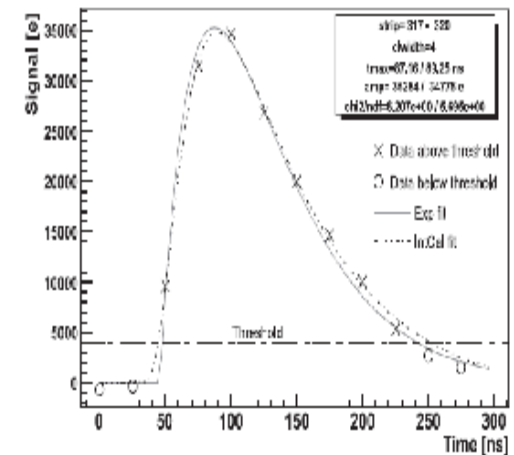
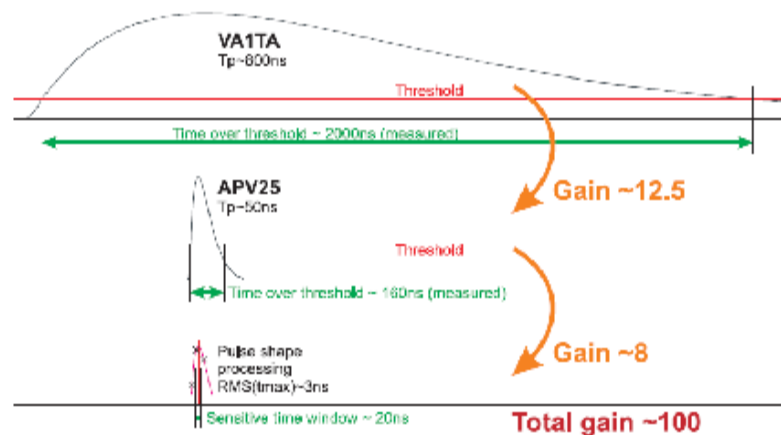
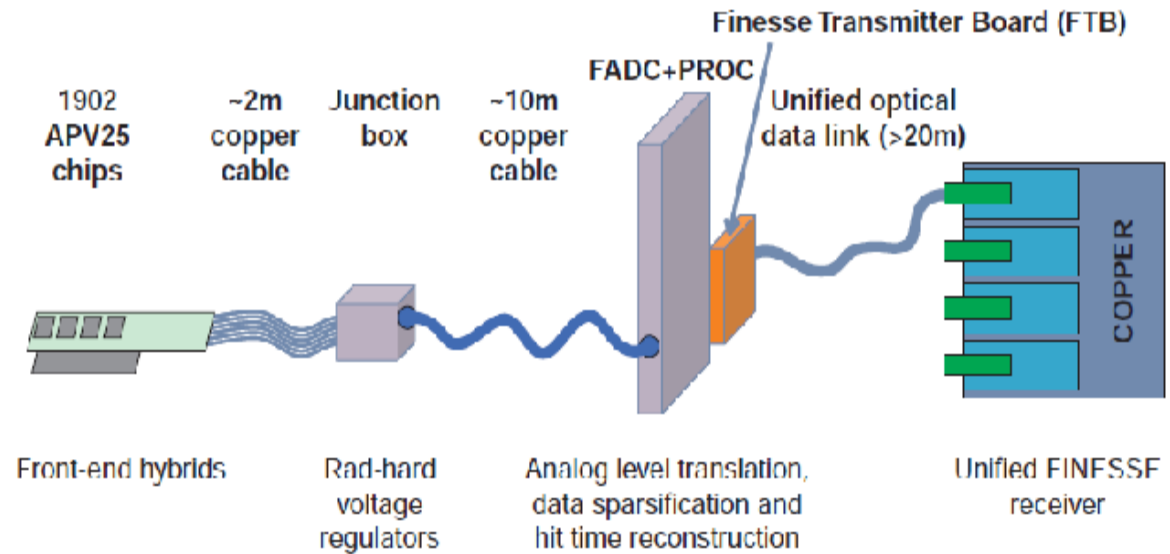
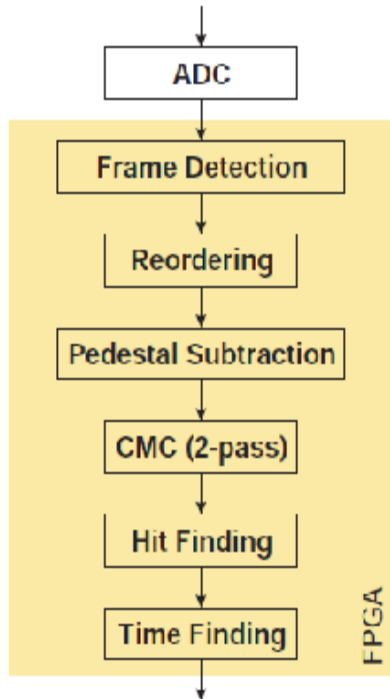


In this talk

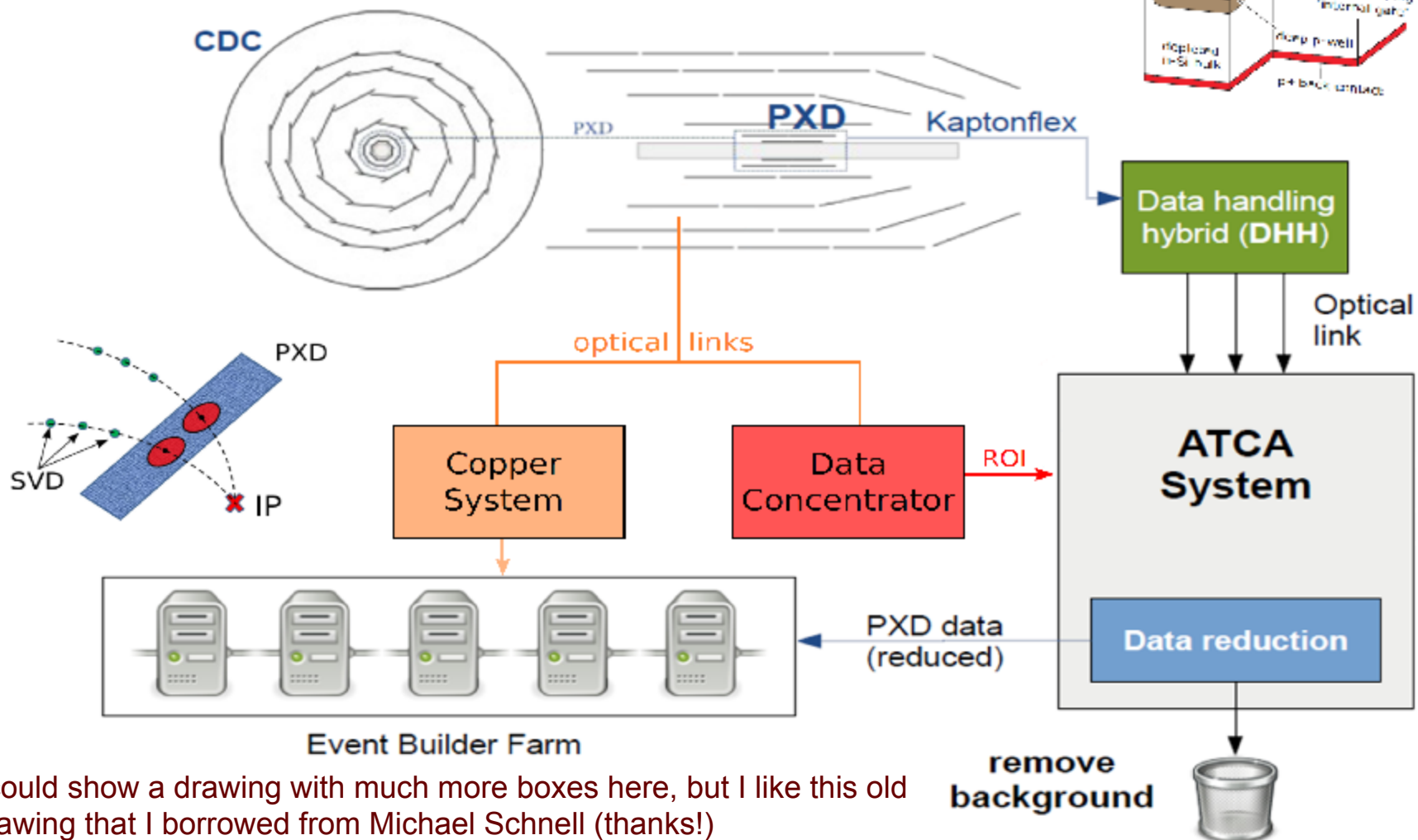
PXD and SVD

1. simulation
 2. clustering
 3. hit reconstruction
- what is implemented
 - what is missing
 - what for the testbeam

SVD and SVD DAQ

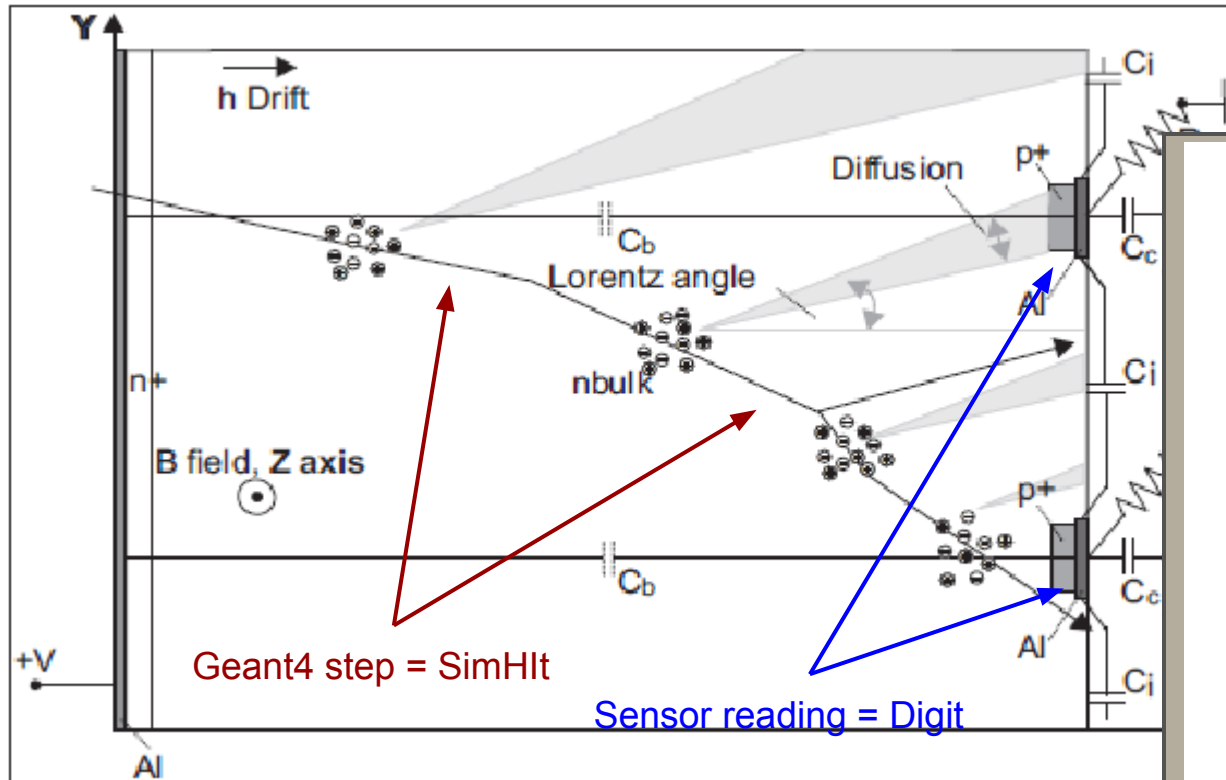


PXD and PXD DAQ



I could show a drawing with much more boxes here, but I like this old drawing that I borrowed from Michael Schnell (thanks!)

PXD and SVD simulation



Drift-to-target model:

- realistic for PXD
- fiction for SVD

Drift of electrons:

$$v(x(t)) = \mu E(x)$$

$$E(x) = - \left(\frac{V + V_{\text{dep}}}{d} - \frac{2xV_{\text{dep}}}{d^2} \right)$$

$$\mu(E(x), T) = \left(\frac{v_m/E_c}{(1 + (E(x)/E_c)^\beta)^{1/\beta}} \right)$$

Lorentz angle:

$$\tan(\vartheta_L) = \frac{\int_x^d \mu(E(x)) r B dx}{\int_x^d dx}$$

Hall factor

$$r = 1.13 + 0.0008(273 - T) \quad \text{for e}$$

Clustering

- Clusters formed from digits with signals over a fixed (zero-suppression) threshold
- (fast) 2D clustering used both for PXD (u, v) and SVD (u/v , time)
- SVDDigits are single APV samples - due to uncertainty about readout modes

PXD/SVD hit position reconstruction

- Simple expressions for hit positions and their uncertainties based on the classical Turchetta's* paper
 - Exception: "Unseen charge" method used to estimate errors in cluster sizes 1,2 for PXD, and 1 in SVD.
 - Cluster shape is taken into account when forming the error covariance matrix for PXD.
- Centre-of-gravity for cluster sizes < 3 , analog head-tail for larger sizes.
- So far:
 - no η correction implemented
 - no special analysis of large clusters,
 - no attempt to merge long clusters

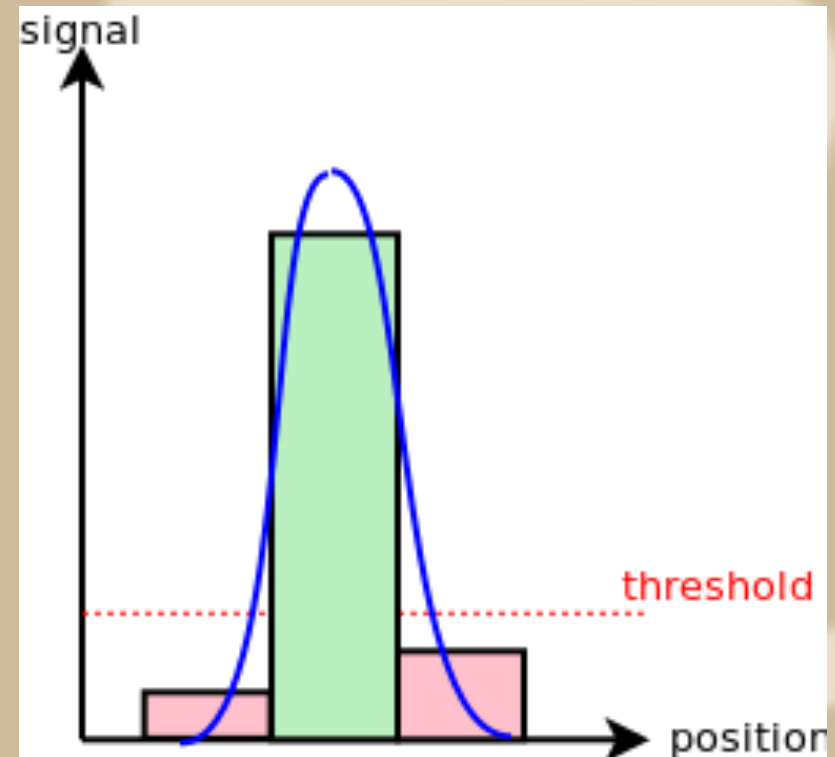
*Turchetta, R. : Spatial resolution of silicon microstrip detectors. Nuclear Instruments and Methods in Physics Research A335 (1993) 44-58

Unseen charge estimate

Motivation:

Estimate position error of a size 1 cluster.

- Position estimate is clear - the centre of the strip/pixel.
- The usual error estimate of $\text{pitch}/\sqrt{12}$ is **wrong**.
- We don't only have the one signal, we also have zero signals in neighbours.
- The higher the signal, the more sure we can be the actual position is near the centre of the pixel/strip.
- The same works to obtain better error estimates for size 2 clusters.



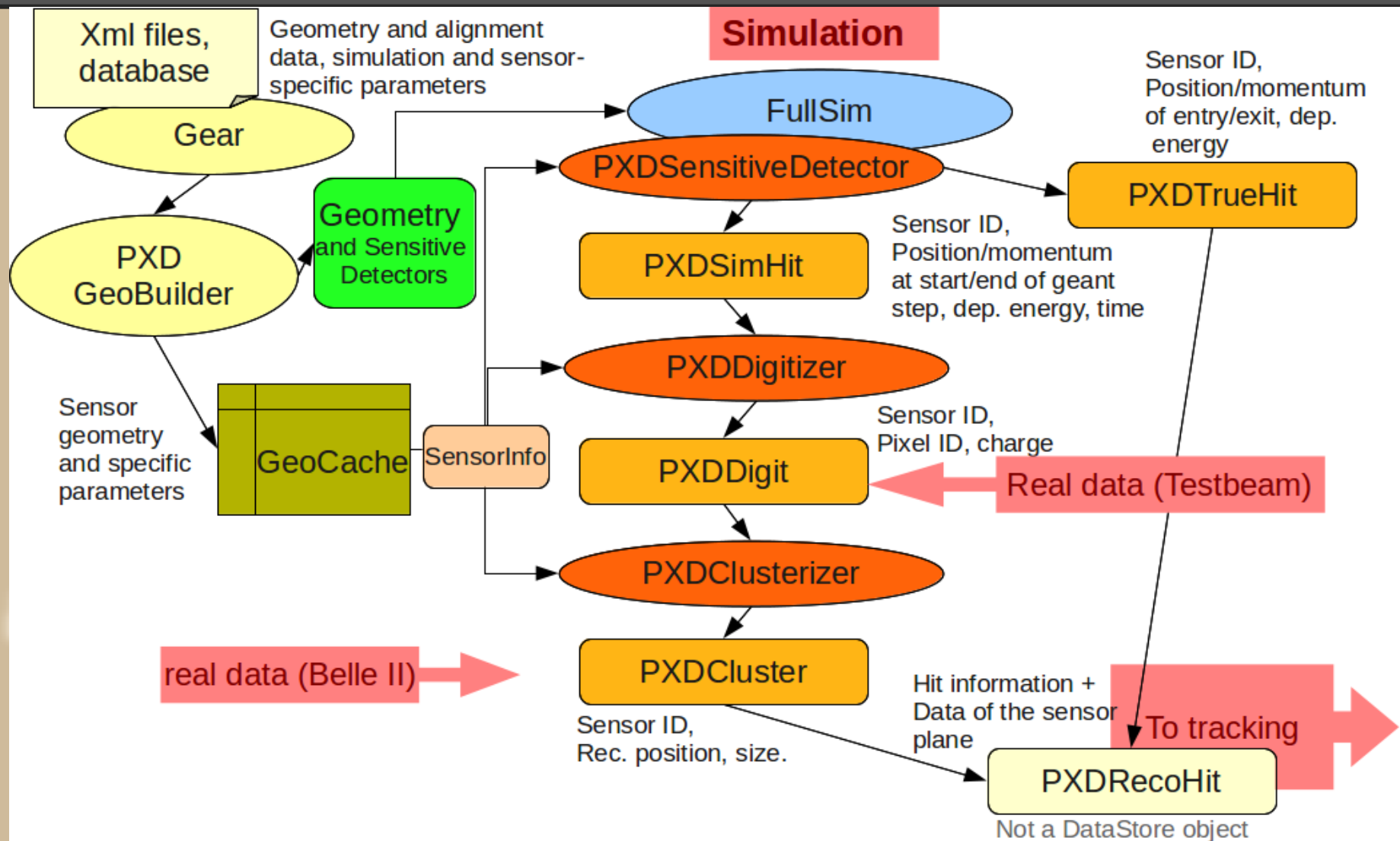
Hit reconstruction in the SVD

Hit position: u_c or v_c	Hit position error: σ_u or σ_v
Positions and their errors are calculated separately for u and v strips. There is no information on correlation. <i>u_i strip position S_i strip signal</i> <i>S cluster charge p strip pitch</i>	
size in u = 1 Center of strip	$\sigma_u = p_u \frac{S_{thr}}{S + S_{thr}}, \quad S_{thr} - 0\text{-suppression cut}$
size in u = 2 $u_c = \frac{S_1 u_1 + S_2 u_2}{S}$	$\sigma_u = a p_u \frac{S_e}{S}, \quad S_e - \text{strip noise}, \quad a = 1.4$
size in u > 2 $u_c = \frac{u_h + u_t}{2} + p_u \frac{S_h - S_t}{2S_0}, \quad S_0 = \sum_i S_i$	$\sigma_u = \frac{p_u}{2} \left[2 \left(\frac{S_{thr}}{S_0} \right)^2 + \frac{1}{2} \left(\frac{S_h}{S_0} \right)^2 + \frac{1}{2} \left(\frac{S_t}{S_0} \right)^2 \right]^{1/2}$
The same formulas are used for v	

Hit reconstruction in the PXD

Hit position: (u_c, v_c)	Hit position error $\begin{pmatrix} \sigma_u^2 & \rho\sigma_u\sigma_v \\ \rho\sigma_u\sigma_v & \sigma_v^2 \end{pmatrix}$
Positions and their errors are calculated separately from cluster projections to each direction. The correlation coefficient is calculated as $\rho = \frac{\sum_{pixels} S_i (u_i - u_c)(v_i - v_c)}{\left(\sum_{pixels} S_i [(u_i - u_c)^2 + \epsilon_u^2] \right)^{1/2} \left(\sum_{pixels} S_i [(v_i - v_c)^2 + \epsilon_v^2] \right)^{1/2}}$	
	(u_i, v_i) pixel positions S_i pixel signals $\epsilon_u = \frac{p_u}{\sqrt{12}}$ in-pixel spread $\epsilon_v = \frac{p_v}{\sqrt{12}}$ in-pixel spread
size in u = 1 Center of pixel	$\sigma_u = p_u \frac{(n_v + 2)S_{thr}}{S + (n_v + 3)S_{thr}}$ n_v cluster size in v S_{thr} 0-supp. threshold
size in u = 2 $u_c = \frac{S_1 u_1 + S_2 u_2}{S}$	$\sigma_u = p_u \frac{(n_v + 2)S_{thr}}{S + (n_v + 3)S_{thr}}$ n_v cluster size in v S_{thr} 0-supp. threshold
size in u > 2 $u_c = \frac{u_h + u_t}{2} + p_u \frac{S_h - S_t}{2S_0}, \quad S_0 = \sum_{i=1}^n S_i$	$\sigma_u = \frac{p_u}{2} \left[2 \left(\frac{S_{thr}}{S_0} \right)^2 + \frac{1}{2} \left(\frac{S_h}{S_0} \right)^2 + \frac{1}{2} \left(\frac{S_t}{S_0} \right)^2 \right]^{1/2}$
The same formulas are used for v	

PXD (and SVD) data processing in basf2: Overview



Data objects

SVDSimHit: Record of a single Geant4 step

```
/** ID of the sensor the energy was deposited in */
unsigned short m_sensorID;
/** PDG Code of the particle producing the Hit */
int m_pdg;
/** Theta angle of particle */
float m_theta;
/** Deposited energy in electrons */
float m_energyDep;
/** Time of energy deposition */
float m_globalTime;
/** Start point of energy deposition in local coordinates */
TVector3 m_posIn;
/** End point of energy deposition in local coordinates */
TVector3 m_posOut;
/** Momentum of particle at start of energy deposition */
TVector3 m_momIn;
```

SVDDigit: Record of a single strip signal sample

```
unsigned short m_sensorID; /**< Compressed sensor identifier.*/
bool m_isU;                /**< True if U, false if V. */
short m_cellID;             /**< Strip coordinate in pitch units. */
float m_cellPosition;       /**< Absolute strip position, -temporary-. */
float m_charge;             /**< Strip signal. */
double m_time;              /**< Time when the sampel was taken. */
```

SVDCluster: A hit reconstructed from strip signals

```
unsigned short m_sensorID; /**< Compressed sensor identifier.*/
bool m_isU;                /**< True if clusters of u-strips, otherwise false. */
float m_position;           /**< Absolute seed strip position in r-phi or z. */
double m_clsTime;          /**< Average waveform maximum time. */
double m_clsTimeSigma;     /**< Standard deviation of waveform maximum times.*/
float m_clsCharge;          /**< Deposited charge in electrons. */
float m_seedCharge;         /**< Cluster seed charge in electrons. */
unsigned short m_clsSize;   /**< Cluster size in pixels */
```

Data objects (cont'd)

VXDTrueHit: Record of a particle passage through a sensor

```
int m_sensorID;           /**< ID of the sensor */
float m_u;                 /**< Local u coordinate when crossing detector plane*/
float m_v;                 /**< Local v coordinate when crossing detector plane*/
float m_entryU;            /**< Local u coordinate when entering silicon */
float m_entryV;            /**< Local v coordinate when entering silicon */
float m_exitU;             /**< Local u coordinate when exiting silicon*/
float m_exitV;             /**< Local v coordinate when exiting silicon*/
float m_energyDep;         /**< Deposited energy while traversing sensor */
float m_globalTime;        /**< Global time. */
TVector3 m_momentum;       /**< momentum in local coordinates when crossing detector plane */
TVector3 m_entryMomentum;  /**< momentum in local coordinates when entering silicon */
TVector3 m_exitMomentum;   /**< momentum in local coordinates when exiting silicon */
```

VxdID: Unique sensor identifier for PXD and SVD

```
union {
    /** Unique id */
    unsigned id: Bits;
    struct {
        /** Segment id */
        unsigned segment: SegmentBits;
        /** Sensor id */
        unsigned sensor: SensorBits;
        /** Ladder id */
        unsigned ladder: LadderBits;
        /** Layer id */
        unsigned layer: LayerBits;
    } parts /**< Struct to contain all id components */;
} m_id; /**< Union to store the ID and all components in one go. */
};
```

What is missing

PXD and SVD

1. Lorentz shift reconstruction (based on local magnetic fields and cluster shapes) - now only very simple versions - we have biases in hit positions. Will improve for the testbeam.
2. Treatment of long clusters - not a priority.

SVD

1. Hit time reconstruction - underway for the testbeam, now only maxima of waveforms.
2. Performance optimization:
 - a. change order of processing cycles
 - b. 6 samples per SVDDigit and 1D clustering (only after the testbeam)

A large, light beige Swastika symbol is centered in the background of the slide. The symbol is composed of four arms bent at right angles, with the top arm pointing to the right. The lines are thick and slightly irregular, giving it a hand-drawn or stylized appearance. The background is a solid, light beige color.

Thank you for attention.